

B.Sc. 5th Semester (Honours) Examination, 2022 (CBCS)

Subject : Physics

Course : DSE-2(3)

(Nano Materials and Applications)

Time: 2 Hours

Full Marks: 40

The figures in the margin indicate full marks.

*Candidates are required to give their answers in their own words
as far as practicable.*

Symbols and abbreviations have their usual meanings.

1. Answer *any five* of the following questions: 2×5=10
- (a) What are the induced effects due to increase in surface area of nanoparticles?
 - (b) Write down the advantages of bottom-up synthesis methods of nanomaterial.
 - (c) Define quantum dot. In which way is it different from an atom?
 - (d) Compare between the traditional optical microscope and electron microscope.
 - (e) An electron beam can undergo diffraction by a crystal. Through what potential should a beam of electron be accelerated so that its wavelength becomes equal to 1.54\AA ?
 - (f) What is Quasi-particle? How does it differ from real particles?
 - (g) State the main differences between edge dislocation and screw dislocation.
 - (h) What are the advantages of nanowire solar cell compared to their bulk counterpart?
2. Answer *any two* of the following questions: 5×2=10
- (a) Briefly explain the meaning of quantum confinement. An electron of energy E is incident on a step potential of height $V_0 = 10\text{ eV}$. Find the transmission coefficient T and reflection coefficient R in the following cases:
 - (i) $E = 7\text{ eV}$
 - (ii) $E = 20\text{ eV}$ 2+3=5
 - (b) What is electrodeposition process for thin film fabrication? What are advantages of this synthesis process? State some applications of electrodeposition method. 1+2+2=5
 - (c) What is the difference between electrical band gap and optical band gap? How are these band gaps measured experimentally? Will they be same for ZnO material? 2+2+1=5
 - (d) Draw the schematic diagram depicting the working principle of any one of the following:
 - (i) Scanning Electron Microscope
 - (ii) Atomic Force Microscope 5

3. Answer any two of the following questions:

10×2=20

- (a) Describe Ball milling process for synthesis of nanoparticles with a neat sketch. List the factors influencing the size of the products in ball mill. 7+3=10
- (b) (i) Explain briefly the method of determining crystallite size from XRD spectrum using Scherrer's formula. Calculate crystallite size of nanoparticle with FWHM = 0.14 deg, $\lambda = 0.154$ nm and $\theta = 45$ deg.
- (ii) Derive necessary formula for indexing X-ray diffraction patterns obtained from materials with a cubic structure. (4+2)+4=10
- (c) (i) What is meant by hopping conduction? Explain why the hopping process is variable.
- (ii) State Mott's law of variable range hopping conduction. What are the important assumptions in deriving Mott's law? Under what conditions, Mott's law is valid? 3+7=10
- (d) Discuss briefly the major applications of quantum dots (QDs) in LED. Outline the applications of QDs in bioimaging. Why are QDs beneficial for photovoltaic devices? 4+4+2=10
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